## Features

- 30MHz -3dB bandwidth
- Supply voltage $=4.5 \mathrm{~V}$ to 16.5 V
- Low supply current (per amplifier) $=2.5 \mathrm{~mA}$
- High slew rate $=33 \mathrm{~V} / \mu \mathrm{s}$
- Unity-gain stable
- Beyond the rails input capability
- Rail-to-rail output swing
- Available in both standard and space-saving fine pitch packages


## Applications

- Driver for A-to-D Converters
- Data Acquisition
- Video Processing
- Audio Processing
- Active Filters
- Test Equipment
- Battery Powered Applications
- Portable Equipment


## Ordering Information

| Part No. | Package | Tape \& Reel | Outline \# |
| :--- | :---: | :---: | :---: |
| EL5210CS | 8-Pin SOIC | - | MDP0027 |
| EL5210CS-T13 | 8-Pin SOIC | $13^{\prime \prime}$ | MDP0027 |
| EL5210CY | 8-Pin MSOP | - | MDP0043 |
| EL5210CY-T7 | 8-Pin MSOP | $7 \prime$ | MDP0043 |
| EL5210CY-T13 | 8-Pin MSOP | $13^{\prime \prime}$ | MDP0043 |
| EL5410CS | 14-Pin SOIC | - | MDP0027 |
| EL5410CS-T13 | 14-Pin SOIC | $13^{\prime \prime}$ | MDP0027 |
| EL5410CR | 14-Pin TSSOP | - | MDP0044 |
| EL5410CR-T13 | 14-Pin TSSOP | $13 "$ | MDP0044 |

## EL5210C/EL5410C

## 30MHz Rail-to-Rail Input-Output Op Amps

## Absolute Maximum Ratings $\left(\mathrm{T}_{\mathrm{A}}=5^{5^{\circ} \mathrm{C}}\right)$

Values beyond absolute maximum ratings can cause the device to be prematurely damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
Supply Voltage between $\mathrm{V}_{\mathrm{S}}+$ and $\mathrm{V}_{\mathrm{S}}-$
$+18 \mathrm{~V}$
Input Voltage
Maximum Continuous Output Current

Maximum Die Temperature
$+125^{\circ} \mathrm{C}$
Storage Temperature $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Operating Temperature
Power Dissipation
ESD Voltage
See Curves
2kV

## Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $\mathbf{T}_{J}=\mathbf{T}_{C}=\mathbf{T}_{A}$

## Electrical Characteristics

$V_{S^{+}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}}=\mathbf{= - 5} \mathrm{V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{L}}=12 \mathrm{pF}$ to $0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| Parameter | Description | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Characteristics |  |  |  |  |  |  |
| V ${ }_{\text {OS }}$ | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 3 | 15 | mV |
| $\mathrm{TCV}_{\text {OS }}$ | Average Offset Voltage Drift ${ }^{[1]}$ |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ |  | 2 | 60 | nA |
| $\mathrm{R}_{\text {IN }}$ | Input Impedance |  |  | 1 |  | G $\Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -5.5 |  | +5.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -5.5 V to 5.5 V | 50 | 70 |  | dB |
| AVOL | Open-Loop Gain | $-4.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.5 \mathrm{~V}$ | 65 | 80 |  | dB |
| Output Characteristics |  |  |  |  |  |  |
| $\mathrm{V}_{\mathrm{OL}}$ | Output Swing Low | $\mathrm{I}_{\mathrm{L}}=-5 \mathrm{~mA}$ |  | -4.9 | -4.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA}$ | 4.8 | 4.9 |  | V |
| $\mathrm{I}_{\text {SC }}$ | Short Circuit Current |  |  | $\pm 120$ |  | mA |
| Iout | Output Current |  |  | $\pm 30$ |  | mA |
| Power Supply Performance |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from $\pm 2.25 \mathrm{~V}$ to $\pm 7.75 \mathrm{~V}$ | 60 | 80 |  | dB |
| IS | Supply Current (Per Amplifier) | No Load |  | 2.5 | 3.75 | mA |
| Dynamic Performance |  |  |  |  |  |  |
| SR | Slew Rate ${ }^{[2]}$ | $-4.0 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.0 \mathrm{~V}, 20 \%$ o $80 \%$ |  | 33 |  | $\mathrm{V} / \mu \mathrm{s}$ |
| $\mathrm{t}^{\text {S }}$ | Settling to $+0.1 \%\left(\mathrm{~A}_{\mathrm{V}}=+1\right)$ | ( $\left.\mathrm{A}_{\mathrm{V}}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ Step |  | 140 |  | ns |
| BW | -3dB Bandwidth |  |  | 30 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 20 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | - |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.12 |  | \% |
| $\mathrm{d}_{\mathrm{P}}$ | Differential Phase ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.17 |  | - |

1. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

## Electrical Characteristics

$\mathrm{V}_{\mathrm{S}^{+}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{L}}=12 \mathrm{pF}$ to $2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| Parameter | Description | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Characteristics |  |  |  |  |  |  |
| V ${ }_{\text {OS }}$ | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$ |  | 3 | 15 | mV |
| $\mathrm{TCV}_{\text {OS }}$ | Average Offset Voltage Drift ${ }^{[1]}$ |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$ |  | 2 | 60 | nA |
| $\mathrm{R}_{\text {IN }}$ | Input Impedance |  |  | 1 |  | G $\Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -0.5 |  | +5.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -0.5 V to 5.5 V | 45 | 66 |  | dB |
| Avol | Open-Loop Gain | $0.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4.5 \mathrm{~V}$ | 65 | 80 |  | dB |
| Output Characteristics |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | Output Swing Low | $\mathrm{I}_{\mathrm{L}}=-5 \mathrm{~mA}$ |  | 100 | 200 | mV |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{I}_{\mathrm{L}}=5 \mathrm{~mA}$ | 4.8 | 4.9 |  | V |
| ISC | Short Circuit Current |  |  | $\pm 120$ |  | mA |
| I ${ }_{\text {Out }}$ | Output Current |  |  | $\pm 30$ |  | mA |
| Power Supply Performance |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from 4.5 V to 15.5 V | 60 | 80 |  | dB |
| $\mathrm{I}_{\text {S }}$ | Supply Current (Per Amplifier) | No Load |  | 2.5 | 3.75 | mA |
| Dynamic Performance |  |  |  |  |  |  |
| SR | Slew Rate ${ }^{[2]}$ | $1 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 4 \mathrm{~V}, 20 \%$ o $80 \%$ |  | 33 |  | V/us |
| ts | Settling to $+0.1 \%\left(\mathrm{~A}_{V}=+1\right)$ | $\left(\mathrm{A}_{\mathrm{V}}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ Step |  | 140 |  | ns |
| BW | -3dB Bandwidth |  |  | 30 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 20 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | - |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.30 |  | \% |
| dp | Differential Phase ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.66 |  | - |

. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

## EL5210C/EL5410C

## 30MHz Rail-to-Rail Input-Output Op Amps

## Electrical Characteristics

$\mathrm{V}_{\mathrm{S}^{+}}=15 \mathrm{~V}, \mathrm{~V}_{\mathrm{S}^{-}}=0 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{L}}=12 \mathrm{pF}$ to $7.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified.

| Parameter | Description | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Characteristics |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OS }}$ | Input Offset Voltage | $\mathrm{V}_{\mathrm{CM}}=7.5 \mathrm{~V}$ |  | 3 | 15 | mV |
| $\mathrm{TCV}_{\text {OS }}$ | Average Offset Voltage Drift ${ }^{[1]}$ |  |  | 7 |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | $\mathrm{V}_{\mathrm{CM}}=7.5 \mathrm{~V}$ |  | 2 | 60 | nA |
| $\mathrm{R}_{\text {IN }}$ | Input Impedance |  |  | 1 |  | G $\Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | 2 |  | pF |
| CMIR | Common-Mode Input Range |  | -0.5 |  | +15.5 | V |
| CMRR | Common-Mode Rejection Ratio | for $\mathrm{V}_{\text {IN }}$ from -0.5 V to 15.5 V | 53 | 72 |  | dB |
| Avol | Open-Loop Gain | $0.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 14.5 \mathrm{~V}$ | 65 | 80 |  | dB |
| Output Characteristics |  |  |  |  |  |  |
| $\mathrm{V}_{\text {OL }}$ | Output Swing Low | $\mathrm{I}_{\mathrm{L}}=-7.5 \mathrm{~mA}$ |  | 170 | 350 | mV |
| $\mathrm{V}_{\mathrm{OH}}$ | Output Swing High | $\mathrm{I}_{\mathrm{L}}=7.5 \mathrm{~mA}$ | 14.65 | 14.83 |  | V |
| $\mathrm{I}_{\text {SC }}$ | Short Circuit Current |  |  | $\pm 120$ |  | mA |
| Iout | Output Current |  |  | $\pm 30$ |  | mA |
| Power Supply Performance |  |  |  |  |  |  |
| PSRR | Power Supply Rejection Ratio | $\mathrm{V}_{\mathrm{S}}$ is moved from 4.5 V to 15.5 V | 60 | 80 |  | dB |
| $\mathrm{I}_{\text {S }}$ | Supply Current (Per Amplifier) | No Load |  | 2.5 | 3.75 | mA |
| Dynamic Performance |  |  |  |  |  |  |
| SR | Slew Rate ${ }^{[2]}$ | $1 \mathrm{~V} \leq \mathrm{V}_{\text {OuT }} \leq 14 \mathrm{~V}, 20 \%$ o $80 \%$ |  | 33 |  | V/ $\mu \mathrm{s}$ |
| ts | Settling to $+0.1 \%\left(\mathrm{Av}_{\mathrm{v}}=+1\right)$ | $\left(\mathrm{A}_{\mathrm{V}}=+1\right), \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}$ Step |  | 140 |  | ns |
| BW | -3dB Bandwidth |  |  | 30 |  | MHz |
| GBWP | Gain-Bandwidth Product |  |  | 20 |  | MHz |
| PM | Phase Margin |  |  | 50 |  | - |
| CS | Channel Separation | $\mathrm{f}=5 \mathrm{MHz}$ |  | 110 |  | dB |
| $\mathrm{d}_{\mathrm{G}}$ | Differential Gain ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.10 |  | \% |
| dp | Differential Phase ${ }^{[3]}$ | $\mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{G}}=1 \mathrm{k} \Omega$ and $\mathrm{V}_{\text {OUT }}=1.4 \mathrm{~V}$ |  | 0.11 |  | 。 |

1. Measured over operating temperature range
2. Slew rate is measured on rising and falling edges
3. NTSC signal generator used

## Typical Performance Curves

EL5410C Input Offset Voltage Distribution


Input Offset Voltage vs Temperature


Output High Voltage vs Temperature


EL5410C Input Offset Voltage Drift


Input Bias Current vs Temperature


Output Low Voltage vs Temperature


## EL5210C/EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

## Typical Performance Curves



EL5410C Supply Current per Amplifier vs Supply Voltage


Differential Gain and Phase



Slew Rate vs Temperature


EL5410C Supply Current per Amplifier vs Temperature


Harmonic Distortion vs Vop-P


## Typical Performance Curves

Open Loop Gain and Phase vs Frequency


Frequency Response for Various $\mathrm{C}_{\mathrm{L}}$


Maximum Output Swing vs Frequency


## EL5210C/EL5410C <br> 30MHz Rail-to-Rail Input-Output Op Amps

## Typical Performance Curves



Total Harmonic Distortion + Noise vs Frequency



Input Voltage Noise Spectral Density vs Frequency


Channel Separation vs Frequency Response


Settling Time vs Step Size


## Typical Performance Curves

Large Signal Transient Response


Small Signal Transient Response


## EL5210C/EL5410C

30MHz Rail-to-Rail Input-Output Op Amps

## Pin Descriptions



## Applications Information

## Product Description

The EL5210C and EL5410C voltage feedback amplifiers are fabricated using a high voltage CMOS process. They exhibit Rail-to-Rail input and output capability, are unity gain stable and have low power consumption ( 2.5 mA per amplifier). These features make the EL5210C and EL5410C ideal for a wide range of gen-eral-purpose applications. Connected in voltage follower mode and driving a load of $1 \mathrm{k} \Omega$ and 12 pF , the EL5210C and EL5410C have a -3dB bandwidth of 30 MHz while maintaining a $33 \mathrm{~V} / \mu \mathrm{S}$ slew rate. The EL5210C is a dual amplifier while the EL5410C is a quad amplifier.

## Operating Voltage, Input, and Output

The EL5210C and EL5410C are specified with a single nominal supply voltage from 5 V to 15 V or a split supply with its total range from 5 V to 15 V . Correct operation is guaranteed for a supply range of 4.5 V to 16.5 V . Most EL5210C and EL5410C specifications are stable over both the full supply range and operating temperatures of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$. Parameter variations with operating voltage and/or temperature are shown in the typical performance curves.

The input common-mode voltage range of the EL5210C and EL5410C extends 500 mV beyond the supply rails. The output swings of the EL5210C and EL5410C typically extend to within 100 mV of positive and negative supply rails with load currents of 5 mA . Decreasing load currents will extend the output voltage range even closer to the supply rails. Figure 1 shows the input and output waveforms for the device in the unity-gain configuration. Operation is from $+/-5 \mathrm{~V}$ supply with a $1 \mathrm{k} \Omega$ load
connected to GND. The input is a $10 \mathrm{Vp}-\mathrm{p}$ sinusoid. The output voltage is approximately $9.8 \mathrm{~V}_{\mathrm{P}-\mathrm{P}}$.


Figure 1. Operation with Rail-to-Rail Input and Output

## Short Circuit Current Limit

The EL5210C and EL5410C will limit the short circuit current to $+/-120 \mathrm{~mA}$ if the output is directly shorted to the positive or the negative supply. If an output is shorted indefinitely, the power dissipation could easily increase such that the device may be damaged. Maximum reliability is maintained if the output continuous current never exceeds $+/-30 \mathrm{~mA}$. This limit is set by the design of the internal metal interconnects.

## Output Phase Reversal

The EL5210C and EL5410C are immune to phase reversal as long as the input voltage is limited from $\mathrm{V}_{\mathrm{S}^{-}}-$ 0.5 V to $\mathrm{V}_{\mathrm{S}}++0.5 \mathrm{~V}$. Figure 2 shows a photo of the output of the device with the input voltage driven beyond the supply rails. Although the device's output will not change phase, the input's overvoltage should be avoided. If an input voltage exceeds supply voltage by more than 0.6 V , electrostatic protection diodes placed in the input

## EL5210C/EL5410C

stage of the device begin to conduct and overvoltage damage could occur.


Figure 2. Operation with Beyond-the-Rails Input

## Power Dissipation

With the high-output drive capability of the EL5210C and EL5410C amplifiers, it is possible to exceed the $125^{\circ} \mathrm{C}$ 'absolute-maximum junction temperature' under certain load current conditions. Therefore, it is important to calculate the maximum junction temperature for the application to determine if load conditions need to be modified for the amplifier to remain in the safe operating area.

The maximum power dissipation allowed in a package is determined according to:

$$
\mathrm{P}_{\mathrm{DMAX}}=\frac{\mathrm{T}_{\mathrm{JMAX}}-\mathrm{T}_{\mathrm{AMAX}}}{\Theta_{\mathrm{JA}}}
$$

Where:
$\mathrm{T}_{\mathrm{JMAX}}=$ Maximum Junction Temperature
$\mathrm{T}_{\mathrm{AMAX}}=$ Maximum Ambient Temperature
$\Theta_{\mathrm{JA}}=$ Thermal Resistance of the Package
$\mathrm{P}_{\mathrm{DMAX}}=$ Maximum Power Dissipation in the
Package.

The maximum power dissipation actually produced by an IC is the total quiescent supply current times the total
power supply voltage, plus the power in the IC due to the loads, or:

$$
\mathrm{P}_{\text {DMAX }}=\Sigma_{\mathrm{i}}\left[\mathrm{~V}_{\mathrm{S}} \times \mathrm{I}_{\text {SMAX }}+\left(\mathrm{V}_{\mathrm{S}^{+}}-\mathrm{v}_{\text {OUT }}{ }^{\mathrm{i}}\right) \times \mathrm{I}_{\text {LOAD }}{ }^{\mathrm{i}]}\right.
$$

when sourcing, and
when sinking.
Where:
$\mathrm{i}=1$ to 2 for Dual and 1 to 4 for Quad
$\mathrm{V}_{\mathrm{S}}=$ Total Supply Voltage
ISMAX $=$ Maximum Supply Current Per Amplifier
$\mathrm{V}_{\text {Out }}{ }^{\mathrm{i}}=$ Maximum Output Voltage of the
Application

$$
\mathrm{I}_{\text {LOAD }} \mathrm{i}=\text { Load current }
$$

If we set the two $\mathrm{P}_{\text {DMAX }}$ equations equal to each other, we can solve for R ROADi to avoid device overheat. Figure 3 and Figure 4 provide a convenient way to see if the device will overheat. The maximum safe power dissipation can be found graphically, based on the package type and the ambient temperature. By using the previous equation, it is a simple matter to see if $\mathrm{P}_{\mathrm{DMAX}}$ exceeds the device's power derating curves. To ensure proper operation, it is important to observe the recommended derating curves shown in Figure 3 and Figure 4.


Figure 3. Package Power Dissipation vs Ambient Temperature


Figure 4. Package Power Dissipation vs Ambient Temperature

## Unused Amplifiers

It is recommended that any unused amplifiers in a dual and a quad package be configured as a unity gain fol-
lower. The inverting input should be directly connected to the output and the non-inverting input tied to the ground plane.

## Driving Capacitive Loads

The EL5210C and EL5410C can drive a wide range of capacitive loads. As load capacitance increases, however, the -3 dB bandwidth of the device will decrease and the peaking increase. The amplifiers drive 10 pF loads in parallel with $1 \mathrm{k} \Omega$ with just 1.2 dB of peaking, and 100 pF with 6.5 dB of peaking. If less peaking is desired in these applications, a small series resistor (usually between $5 \Omega$ and $50 \Omega$ ) can be placed in series with the output. However, this will obviously reduce the gain slightly. Another method of reducing peaking is to add a "snubber" circuit at the output. A snubber is a shunt load consisting of a resistor in series with a capacitor. Values of $150 \Omega$ and 10 nF are typical. The advantage of a snubber is that it does not draw any DC load current or reduce the gain

## Power Supply Bypassing and Printed Circuit Board Layout

The EL5210C and EL5410C can provide gain at high frequency. As with any high-frequency device, good printed circuit board layout is necessary for optimum performance. Ground plane construction is highly recommended, lead lengths should be as short as possible and the power supply pins must be well bypassed to reduce the risk of oscillation. For normal single supply operation, where the $\mathrm{V}_{\mathrm{S}^{-}}$pin is connected to ground, a $0.1 \mu \mathrm{~F}$ ceramic capacitor should be placed from $\mathrm{V}_{\mathrm{S}}+$ to pin to $\mathrm{V}_{\mathrm{S}}$ pin. A $4.7 \mu \mathrm{~F}$ tantalum capacitor should then be connected in parallel, placed in the region of the amplifier. One $4.7 \mu \mathrm{~F}$ capacitor may be used for multiple devices. This same capacitor combination should be placed at each supply pin to ground if split supplies are to be used.

## General Disclaimer

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